Infrared Emitter (850 nm) Version 1.4

SFH 4554



Features:

- Wavelength 860nm
- Narrow half angle ± 10°
- · Short switching times
- UL version available (details & test conditions on request)

Applications

- · Infrared Illumination for cameras
- Sensor technology
- · Data transmission

Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Ordering Information

Туре:	Radiant Intensity	Ordering Code
	I _e [mW/sr]	
	I _F = 100 mA, t _p = 20 ms	
SFH 4554	550 (≥ 250)	Q65111A4885
SFH 4554-CW/DW/EW E9548 (UL)	550 (≥ 250)	Q65112A0342
SFH 4554-CWDW	250 800	Q65111A7922
SFH 4554-DWEW	400 1250	Q65111A9145

Note: Measured at a solid angle of $\Omega = 0.001$ sr



$\underline{\text{Maximum Ratings}} \; (\mathsf{T_A} = 25 \; ^{\circ}\mathsf{C})$

Parameter	Symbol	Values	Unit
Operation and storage temperature range	T _{op} ; T _{stg}	-40 100	°C
Reverse voltage	V _R	5	V
Forward current	I _F	100	mA
Surge current $(t_p \le 200 \ \mu s, \ D = 0)$	I _{FSM}	1	A
Power consumption	P _{tot}	200	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2	kV
Thermal resistance junction - ambient 1) page 8	R _{thJA}	430	K/W
Thermal resistance junction - soldering point	R _{thJS}	240	K/W

Characteristics $(T_A = 25 \, ^{\circ}C)$

Parameter		Symbol	Values	Unit
Peak wavelength (I _F = 100 mA, t _p = 20 ms)	(typ)	λ_{peak}	860	nm
Centroid wavelength (I _F = 100 mA, t _p = 20 ms)	(typ)	$\lambda_{\text{centroid}}$	850	nm
Spectral bandwidth at 50% of I_{max} ($I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$)	(typ)	Δλ	30	nm
Half angle	(typ)	φ	± 10	0
Dimensions of active chip area	(typ)	LxW	0.3 x 0.3	mm x mm
Rise and fall time of I_e (10% and 90% of $I_{e max}$) ($I_F = 100 \text{ mA}, R_L = 50 \Omega$)	(typ)	t _r , t _f	12	ns
Forward voltage $(I_F = 100 \text{ mA}, t_p = 20 \text{ ms})$	(typ (max))	V _F	1.7 (≤ 2)	V
Forward voltage $(I_F = 1A, t_p = 100 \mu s)$	(typ (max))	V _F	3.6 (≤ 4.6)	V
Reverse current (V _R = 5 V)		I _R	not designed for reverse operation	μΑ
Total radiant flux (I _F =100 mA, t _p =20 ms)	(typ)	Фе	75	mW



Parameter		Symbol	Values	Unit
Temperature coefficient of I_e or Φ_e ($I_F = 100$ mA, $t_p = 20$ ms)	(typ)	TC _I	-0.3	% / K
Temperature coefficient of V_F ($I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$)	(typ)	TC _V	-0.6	mV / K
Temperature coefficient of wavelength $(I_F = 100 \text{ mA}, t_p = 20 \text{ ms})$	(typ)	TC_λ	0.3	nm / K

Grouping $(T_A = 25 \, ^{\circ}C)$

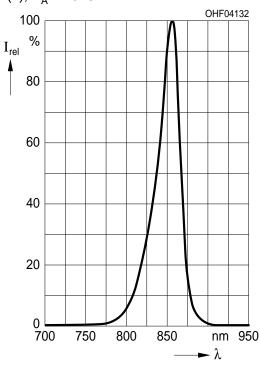
Group	Min Radiant Intensity	Max Radiant Intensity	Typ Radiant Intensity
	I _F = 100 mA, t _p = 20 ms	I _F = 100 mA, t _p = 20 ms	$I_F = 1 A, t_p = 100 \mu s$
	I _{e, min} [mW / sr]	I _{e, max} [mW / sr]	I _{e, typ} [mW / sr]
SFH 4554-CW	250	500	1580
SFH 4554-DW	400	800	2530
SFH 4554-EW	630	1250	3980

Note: Measured at a solid angle of $\Omega = 0.001$ sr

Only one group in one packing unit (variation lower 2:1).

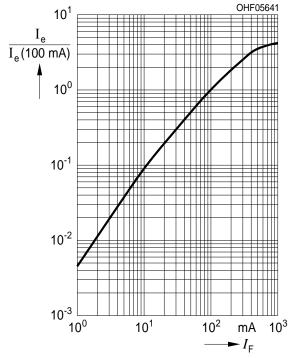
Relative Spectral Emission 2) page 8

$$I_{rel} = f(\lambda), T_A = 25^{\circ}C$$



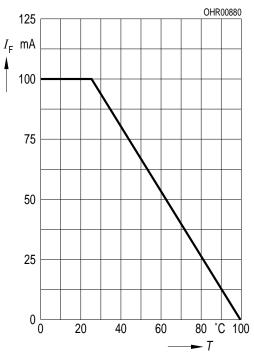
Radiant Intensity 2) page 8

$$\rm I_e$$
 / $\rm I_e(100~mA)$ = f(I_F), single pulse, t_p = 100 µs, T_A= 25°C



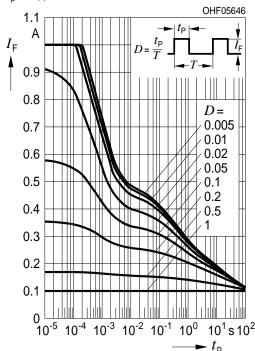
Max. Permissible Forward Current

 $I_{F, \text{max}} = f(T_A), R_{thJA} = 430 \text{ K} / \text{W}$



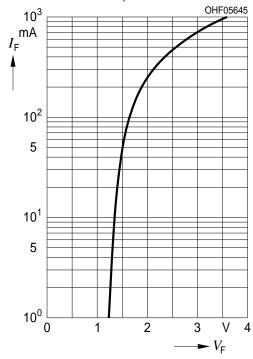
Permissible Pulse Handling Capability

 $I_F = f(t_p)$, $T_A = 25$ °C, duty cycle D = parameter



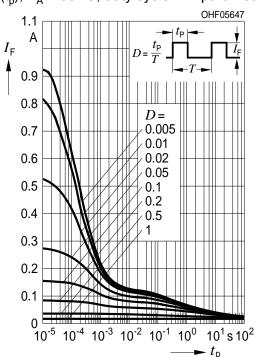
Forward Current 2) page 8

 I_F = f(V_F), single pulse, t_p = 100 μ s, T_A = 25°C



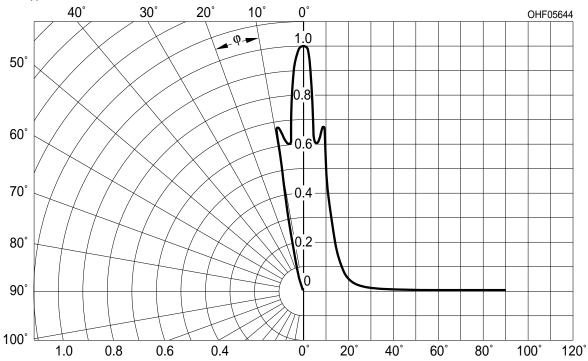
Permissible Pulse Handling Capability

 $I_F = f(t_p)$, $T_A = 85$ °C, duty cycle D = parameter

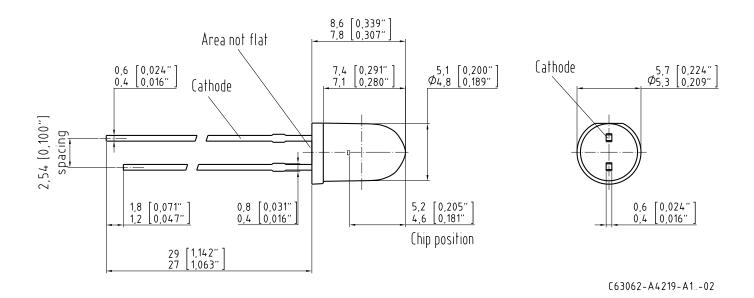


Radiation Characteristics 2) page 8

$$I_{rel} = f(\phi), T_A = 25^{\circ}C$$



Package Outline



Dimensions in mm (inch).

Package

5mm Radial (T 1 3/4), Epoxy

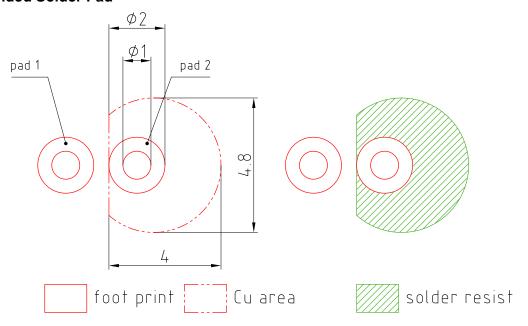
Approximate Weight:

0.3 g

Note

Packing information is available on the internet (online product catalog).

Recommended Solder Pad



E062.3010.188-01

Dimensions in mm.

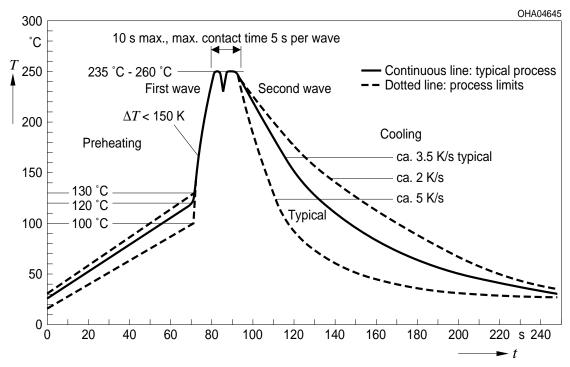
Note:

pad 1: cathode



TTW Soldering

IEC-61760-1 TTW



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

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- **) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

1) Thermal resistance: junction -ambient, mounted on PC-board (FR4), padsize 16 mm² each

Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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